

UNISONIC TECHNOLOGIES CO., LTD

80N06

Preliminary

80A, 60V N-CHANNEL POWER MOSFET

DESCRIPTION

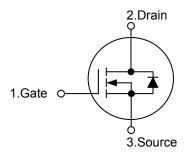
The UTC **80N06** is an N-channel MOSFET using UTC advanced technology.

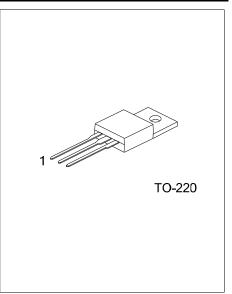
The UTC **80N06** is suitable for power supply (secondary synchronous rectification), industrial and primary switch etc.

FEATURES

* $R_{DS(ON)}$ < 8.5m Ω @ V_{GS} = 10 V, I_D = 40 A

SYMBOL





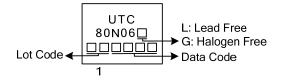
ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Deaking
Lead Free	Halogen Free	Package	1	2	3	Packing
80N06L-TA3-T	80N06G-TA3-T	TO-220	G	D	S	Tube
Note: Pin Assignment: G: G						

80N06L-TA3-T (1)Packing Type (1) T: Tube (2)Package Type (2) TA3: TO-220

(3)Green Package (3) L: Lead Free, G: Halogen Free and Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_c=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V _{DSS}	60	V	
Gate-Source Voltage		V _{GSS}	±20	V	
Continuous Drain Current	Continuous	ID	80	А	
Pulsed Drain Current	Pulsed (Note 2)	I _{DM}	320	А	
Avalanche Current (Note 3)		I _{AR}	58	А	
Avalanche energy	Single Pulsed (Note 3)	E _{AS}	168	mJ	
Peak Diode Recovery dv/dt (Note 4)		dv/dt	6.0	V/nS	
Power Dissipation		PD	200	W	
Junction Temperature		TJ	+150	°C	
Storage Temperature Range		T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. L=0.1mH, I_{AS}=58A, V_{DD}=50V, R_G=25 Ω , Starting T_J = 25°C.

4. $I_{SD} \leq 30A$, di/dt $\leq 200A/\mu s$, $V_{DD} \leq V_{(BR)DSS}$, $T_J = 25^{\circ}C$.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ _{JC} 0.625		°C/W	

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

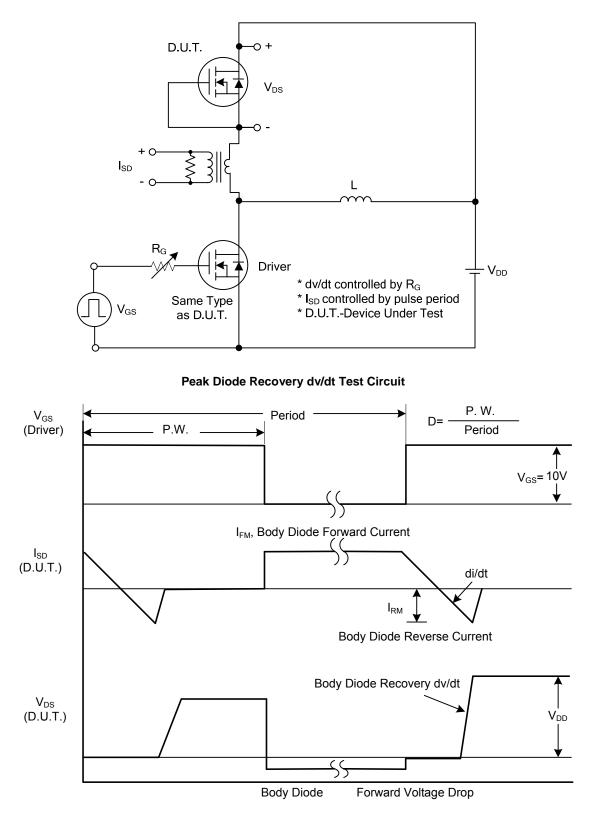
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250µA, V _{GS} =0V	60			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA
Gate-Source Leakage Current	I _{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			±100	nA
ON CHARACTERISTICS	_					
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250µA			4.0	V
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A			8.5	mΩ
DYNAMIC PARAMETERS	_		_		_	
Input Capacitance	C _{ISS}			3500		pF
Output Capacitance	Coss	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		370		рF
Reverse Transfer Capacitance	C _{RSS}	7		295		pF
SWITCHING PARAMETERS						
Total Gate Charge (Note 1)	Q_{G}	−V _{DS} =50V, V _{GS} =10V, I _D =1.3A, − −I _D =100µA (Note 1, 2)		308		nC
Gate to Source Charge	Q _{GS}			12		nC
Gate to Drain Charge	Q_{GD}			45		nC
Turn-on Delay Time (Note 1)	t _{D(ON)}	_V _{DS} =30V, V _{GS} =10V, I _D =0.5A, R _G =25Ω (Note 1, 2)		45		ns
Rise Time	t _R			76		ns
Turn-off Delay Time	t _{D(OFF)}			155		ns
Fall-Time	t⊨	7		473		ns
SOURCE- DRAIN DIODE RATINGS AND CH	ARACTERIS	TICS				
Maximum Body-Diode Continuous Current	ls				80	Α
Maximum Body-Diode Pulsed Current	I _{SM}	7			320	Α
Drain-Source Diode Forward Voltage (Note 1)	V _{SD}	I _S =80A, V _{GS} =0V			1.2	V
Reverse Recovery Time (Note 1)	trr	I _S =30A, V _{GS} =0V,		90		ns
Reverse Recovery Charge	Qrr	dI _F /dt=100A/µs		110		nC
Notes: 1 Pulse Test : Pulse width < 300us. Du	$\frac{1}{10000000000000000000000000000000000$	•				

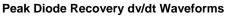
Notes: 1. Pulse Test : Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating temperature.



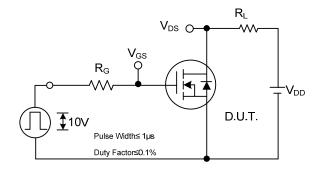
■ TEST CIRCUITS AND WAVEFORMS

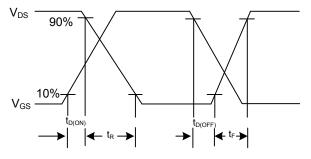






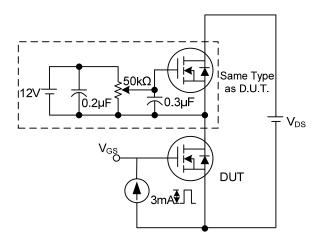
TEST CIRCUITS AND WAVEFORMS (Cont.)



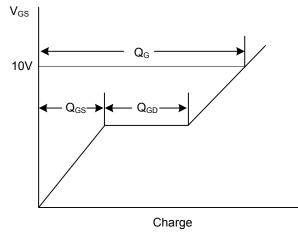


Switching Test Circuit

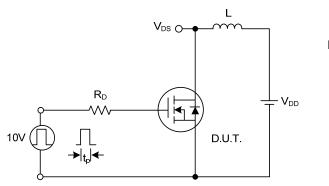




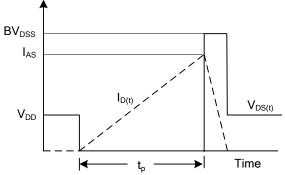




Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

